

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCX16244FT

Low-Voltage 16-Bit Bus Buffer with 5-V Tolerant Inputs and Outputs

The TC74LCX16244FT is a high-performance CMOS 16-bit bus buffer. Designed for use in 2.5-V or 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

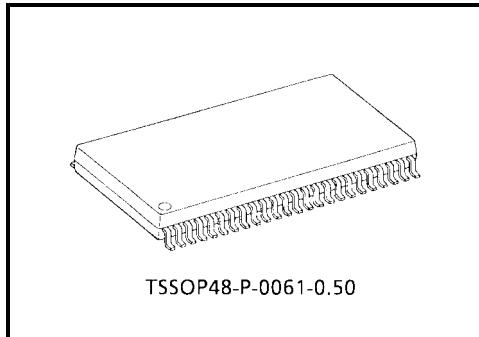
The device is designed for low-voltage (2.5-V or 3.3-V) VCC applications, but it could be used to interface to 5 V supply environment for both inputs and outputs.

This device is non-inverting 3-state buffer having four active-low output enables. It can be used as four 4-bit buffers two 8-bit buffers or one 16-bit buffer. When the \overline{OE} input is high, the outputs are in a high-impedance state. This device is designed to be used with 3-state memory address drivers, etc.

All inputs are equipped with protection circuits against static discharge.

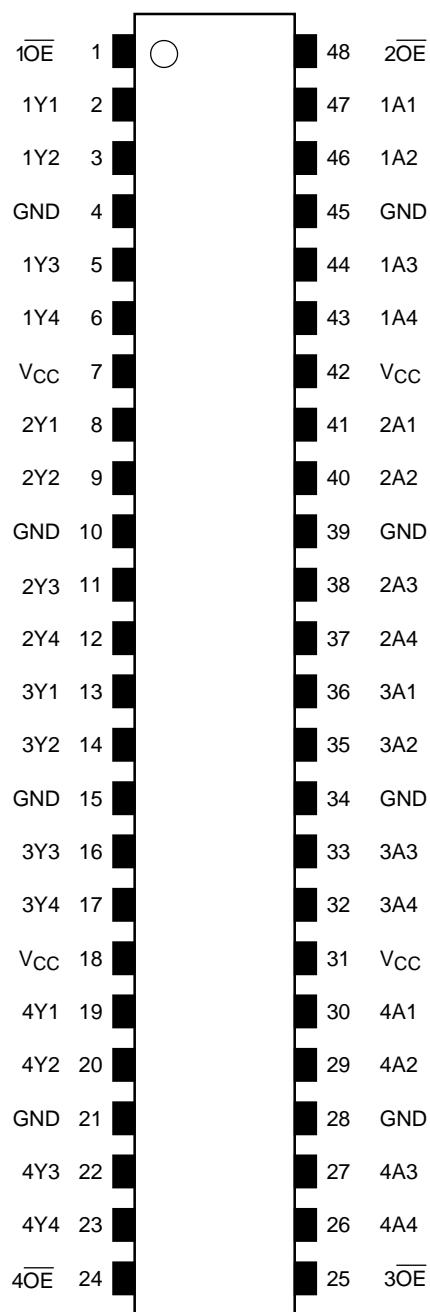
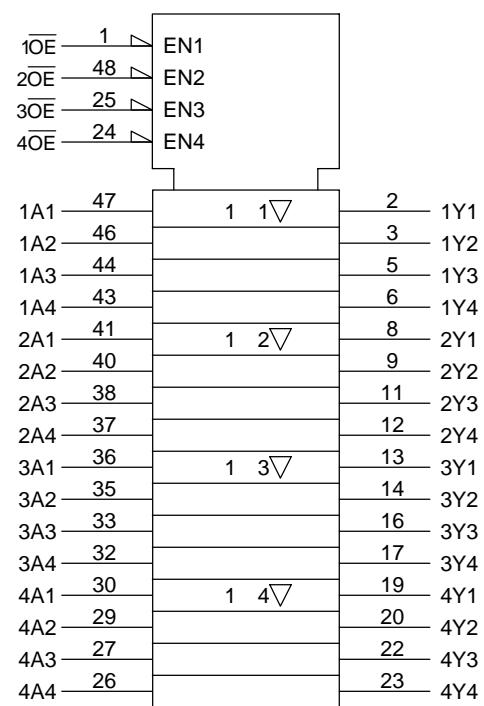
Features

- Low-voltage operation: $V_{CC} = 2.0$ to 3.6 V
- High-speed operation: $t_{pd} = 4.5$ ns (max) ($V_{CC} = 3.0$ to 3.6 V)
- Output current: $|I_{OH}|/I_{OL} = 24$ mA (min) ($V_{CC} = 3.0$ V)
- Latch-up performance: ± 500 mA
- Package: TSSOP (thin shrink small outline package)
- Power-down protection provided on all inputs and outputs



TSSOP48-P-0061-0.50

Weight: 0.25 g (typ.)

Pin Assignment (top view)**IEC Logic Symbol**

Truth Table

Inputs		Outputs
$1\bar{OE}$	1A1-1A4	1Y1-1Y4
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$2\bar{OE}$	2A1-2A4	2Y1-2Y4
L	L	L
L	H	H
H	X	Z

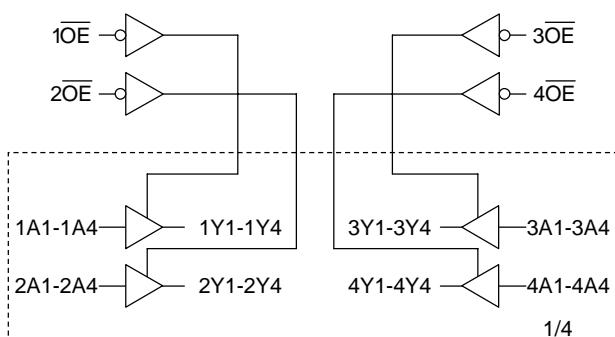
Inputs		Outputs
$3\bar{OE}$	3A1-3A4	3Y1-3Y4
L	L	L
L	H	H
H	X	Z

Inputs		Outputs
$4\bar{OE}$	4A1-4A4	4Y1-4Y4
L	L	L
L	H	H
H	X	Z

X: Don't care

Z: High impedance

System Diagram



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Maximum Ratings

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	−0.5 to 6.0	V
Input voltage	V _{IN}	−0.5 to 7.0	V
Output voltage	V _{OUT}	−0.5 to 7.0 (Note 1)	V
		−0.5 to V _{CC} + 0.5 (Note 2)	
Input diode current	I _{IK}	−50	mA
Output diode current	I _{OK}	±50 (Note 3)	mA
DC output current	I _{OUT}	±50	mA
Power dissipation	P _D	400	mW
DC V _{CC} /ground current per supply pin	I _{CC} /I _{GND}	±100	mA
Storage temperature	T _{stg}	−65 to 150	°C

Note 1: Output in OFF state

Note 2: High or low state. I_{OUT} absolute maximum rating must be observed.

Note 3: V_{OUT} < GND, V_{OUT} > V_{CC}

Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	2.0 to 3.6	V
		1.5 to 3.6 (Note 4)	
Input voltage	V _{IN}	0 to 5.5	V
Output voltage	V _{OUT}	0 to 5.5 (Note 5)	V
		0 to V _{CC} (Note 6)	
Output current	I _{OH} /I _{OL}	±24 (Note 7)	mA
		±12 (Note 8)	
		±8 (Note 9)	
Operating temperature	T _{opr}	−40 to 85	°C
Input rise and fall time	dt/dv	0 to 10 (Note 10)	ns/V

Note 4: Data retention only

Note 5: Output in OFF state

Note 6: High or low state

Note 7: V_{CC} = 3.0 to 3.6 V

Note 8: V_{CC} = 2.7 to 3.0 V

Note 9: V_{CC} = 2.3 to 2.7 V

Note 10: V_{IN} = 0.8 to 2.0 V, V_{CC} = 3.0 V

Electrical Characteristics**DC Characteristics (Ta = -40 to 85°C)**

Characteristics		Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit		
Input voltage	H-level				2.3 to 2.7	1.7			
	L-level				2.7 to 3.6	2.0			
	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -100 µA	2.3 to 3.6	V _{CC} -0.2	V		
	L-level			I _{OH} = -8 mA	2.3	1.8			
	H-level			I _{OH} = -12 mA	2.7	2.2			
	L-level			I _{OH} = -18 mA	3.0	2.4			
	H-level			I _{OH} = -24 mA	3.0	2.2			
	H-level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 µA	2.3 to 3.6	—	µA		
	L-level			I _{OL} = 8 mA	2.3	—			
	H-level			I _{OL} = 12 mA	2.7	—			
	L-level			I _{OL} = 16 mA	3.0	—			
	L-level			I _{OL} = 24 mA	3.0	—			
Input leakage current	I _{IN}	V _{IN} = 0 to 5.5 V			2.3 to 3.6	—	±5.0	µA	
3-state output off-state current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 5.5 V			2.3 to 3.6	—	±5.0	µA	
Power off leakage current	I _{OFF}	V _{IN} /V _{OUT} = 5.5 V			0	—	10.0	µA	
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND			2.3 to 3.6	—	20.0	µA	
		V _{IN} /V _{OUT} = 3.6 to 5.5 V			2.3 to 3.6	—	±20.0		
Increase in I _{CC} per input	ΔI _{CC}	V _{IH} = V _{CC} - 0.6 V			2.3 to 3.6	—	500		

AC Characteristics (Ta = -40 to 85°C)

Characteristics		Symbol	Test Condition	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	t _{pLH} t _{pHL}	Figure 1, Figure 2		2.5 ± 0.2	30	1.5	5.4	ns
				2.7	50	1.5	5.2	
				3.3 ± 0.3	50	1.5	4.5	
3-state output enable time	t _{pZL} t _{pZH}	Figure 1, Figure 3		2.5 ± 0.2	30	1.5	7.2	ns
				2.7	50	1.5	6.3	
				3.3 ± 0.3	50	1.5	5.5	
3-state output disable time	t _{pLZ} t _{pHZ}	Figure 1, Figure 3		2.5 ± 0.2	30	1.5	6.5	ns
				2.7	50	1.5	5.7	
				3.3 ± 0.3	50	1.5	5.4	
Output to output skew	t _{osLH} t _{osHL}	(Note 11)		2.5 ± 0.2	30	—	—	ns
				2.7	50	—	—	
				3.3 ± 0.3	50	—	1.0	

Note 11: Parameter guaranteed by design.

(tosLH = |t_{pLHm} - t_{pLHn}|, tosHL = |t_{pHLm} - t_{pHLn}|)

Dynamic Switching Characteristics

(Ta = 25°C, input: t_r = t_f = 2.5 ns, R_L = 500 Ω)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Typ.	Unit
Quiet output maximum dynamic	V _{OL}	V _{IH} = 2.5 V, V _{IL} = 0 V, C _L = 30 pF	2.5	0.6	V
		V _{IH} = 3.3 V, V _{IL} = 0 V, C _L = 50 pF	3.3	0.8	
Quiet output minimum dynamic	V _{OL}	V _{IH} = 2.5 V, V _{IL} = 0 V, C _L = 30 pF	2.5	0.6	V
		V _{IH} = 3.3 V, V _{IL} = 0 V, C _L = 50 pF	3.3	0.8	

Capacitive Characteristics (Ta = 25°C)

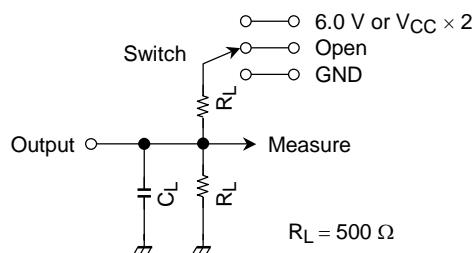
Characteristics	Symbol	Test Condition	V _{CC} (V)	Typ.	Unit
Input capacitance	C _{IN}	—	3.3	7	pF
Output capacitance	C _{OUT}	—	3.3	8	pF
Power dissipation capacitance	C _{PD}	f _{IN} = 10 MHz (Note 12)	3.3	25	pF

Note 12: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC} (\text{opr}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/16 \text{ (per bit)}$$

AC Test Circuit



Parameter	Switch
t_{PLH}, t_{PHL}	Open
t_{PLZ}, t_{PZL}	6.0 V $V_{CC} \times 2$ @ $V_{CC} = 3.3 \pm 0.3$ V @ $V_{CC} = 2.5 \pm 0.2$ V
t_{PHZ}, t_{PZH}	GND

Figure 1

AC Waveform

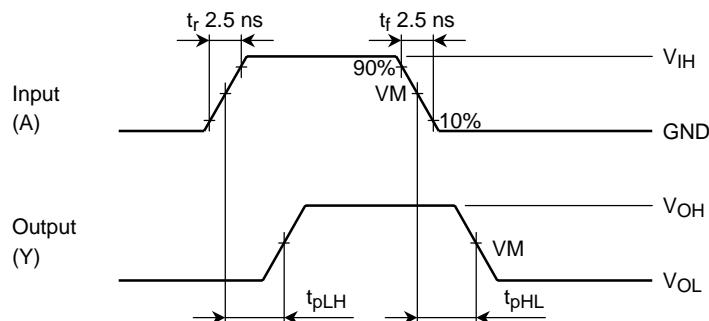


Figure 2 t_{PLH}, t_{PHL}

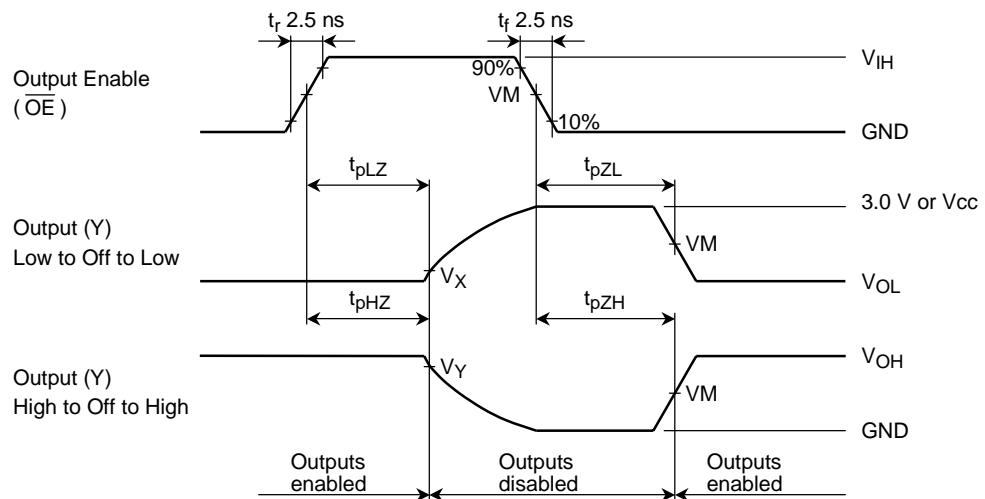


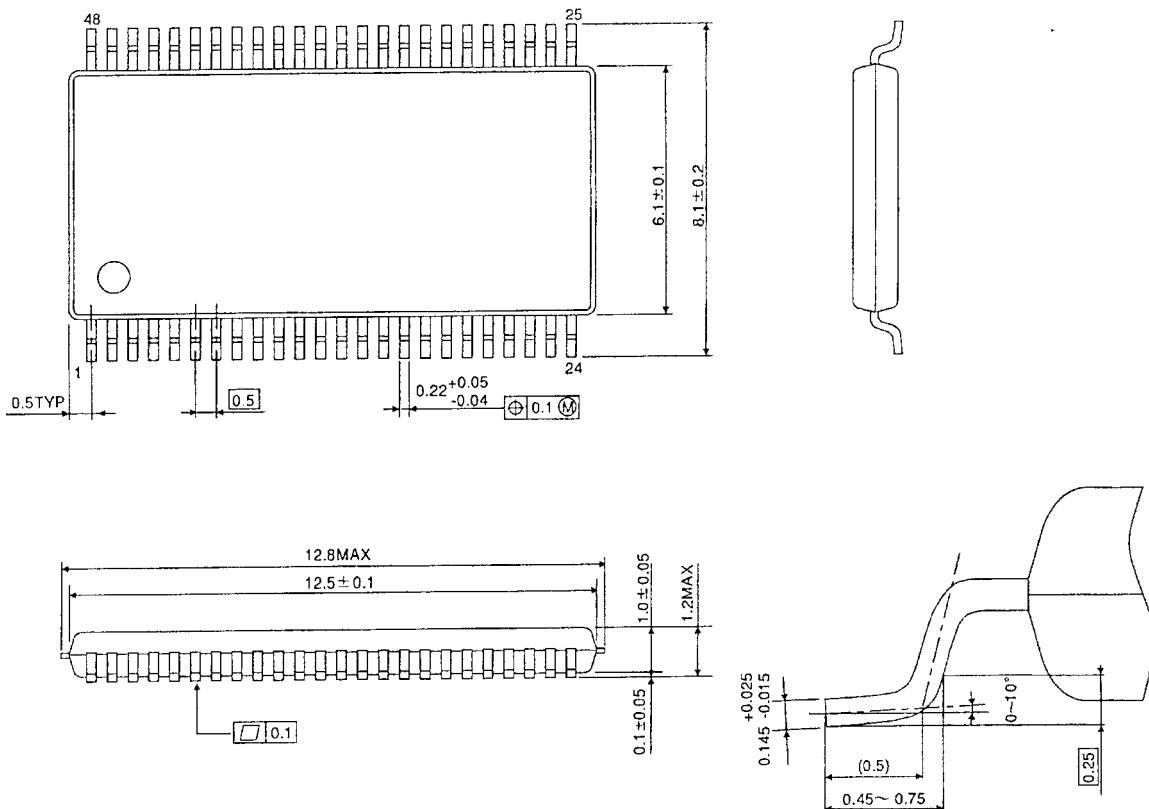
Figure 3 t_{pLZ} , t_{pHZ} , t_{pZL} , t_{pZH}

Symbol	V_{CC}		
	$3.3 \pm 0.3 \text{ V}$	2.7 V	$2.5 \pm 0.2 \text{ V}$
V_{IH}	2.7 V	2.7 V	V_{CC}
V_M	1.5 V	1.5 V	$V_{CC}/2$
V_X	$V_{OL} + 0.3 \text{ V}$	$V_{OL} + 0.3 \text{ V}$	$V_{OL} + 0.15 \text{ V}$
V_Y	$V_{OH} - 0.3 \text{ V}$	$V_{OH} - 0.3 \text{ V}$	$V_{OH} - 0.15 \text{ V}$

Package Dimensions

TSSOP48-P-0061-0.50

Unit : mm



Weight: 0.25 g (typ.)

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